

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China







MBR2060CT and MBR20100CT are Preferred Devices

SWITCHMODE™ Power Rectifiers

This series uses the Schottky Barrier principle with a platinum barrier metal. These state-of-the-art devices have the following features:

Features

- 20 A Total (10 A Per Diode Leg)
- Guard-Ring for Stress Protection
- Low Forward Voltage
- 175°C Operating Junction Temperature
- Epoxy Meets UL 94 V-0 @ 0.125 in
- Low Power Loss/High Efficiency
- High Surge Capacity
- Low Stored Charge Majority Carrier Conduction
- Shipped 50 units per plastic tube
- Pb-Free Packages are Available*

Mechanical Characteristics:

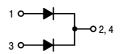
- Case: Epoxy, Molded
- Weight: 1.9 grams (approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds



ON Semiconductor®

http://onsemi.com

SCHOTTKY BARRIER RECTIFIERS 20 AMPERES 60-100 VOLTS





MARKING DIAGRAM



A = Assembly Location

Y = Year

WW = Work Week

B20x0 = Device Code

x = 6, 8, 9 or 10

G = Pb-Free Device

AKA = Polarity Designator

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

Preferred devices are recommended choices for future use and best overall value.

^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

MAXIMUM RATINGS (Per Diode Leg)

Rating		MBR				
	Symbol	2060CT	2080CT	2090CT	20100CT	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	60	80	90	100	V
Average Rectified Forward Current (Rated V _R) T _C = 133°C	I _{F(AV)}	10			Α	
Peak Repetitive Forward Current (Rated V _R , Square Wave, 20 kHz) T _C = 133°C	I _{FRM}	20				Α
Nonrepetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz)	I _{FSM}	150				Α
Peak Repetitive Reverse Surge Current (2.0 μs, 1.0 kHz)	I _{RRM}	0.5			Α	
Operating Junction Temperature (Note 1)	TJ	- 65 to +175		°C		
Storage Temperature	T _{stg}	- 65 to +175			°C	
Voltage Rate of Change (Rated V _R)	dv/dt	10,000			V/μs	
THERMAL CHARACTERISTICS						
Maximum Thermal Resistance Junction-to-Case Junction-to-Ambient	$R_{ heta JC} \ R_{ heta JA}$	2.0 60				°C/W
ELECTRICAL CHARACTERISTICS (Per Diode Leg)	•	•				
Maximum Instantaneous Forward Voltage (Note 2) $ \begin{aligned} &(i_F=10 \text{ Amps, } T_C=125^\circ\text{C})\\ &(i_F=10 \text{ Amps, } T_C=25^\circ\text{C})\\ &(i_F=20 \text{ Amps, } T_C=125^\circ\text{C})\\ &(i_F=20 \text{ Amps, } T_C=25^\circ\text{C}) \end{aligned} $	VF	0.75 0.85 0.85 0.95			V	
Maximum Instantaneous Reverse Current (Note 2) (Rated dc Voltage, $T_C = 125^{\circ}C$) (Rated dc Voltage, $T_C = 125^{\circ}C$ – MBR2060CT only) (Rated dc Voltage, $T_C = 25^{\circ}C$)	i _R	6.0 20 0.1		mA		

^{1.} The heat generated must be less than the thermal conductivity from Junction–to–Ambient: $dP_D/dT_J < 1/R_{\theta JA}$.

ORDERING INFORMATION

Device	Package	Shipping [†]	
MBR2060CT	TO-220		
MBR2060CTG	TO-220 (Pb-Free)	50 Units / Rail	
MBR2080CT	TO-220		
MBR2080CTG	TO-220 (Pb-Free)	50 Units / Rail	
MBR2090CT	TO-220		
MBR2090CTG	TO-220 (Pb-Free)	50 Units / Rail	
MBR20100CT	TO-220		
MBR20100CTG	TO-220 (Pb-Free)	50 Units / Rail	

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

^{2.} Pulse Test: Pulse Width = 300 μ s, Duty Cycle \leq 2.0%.

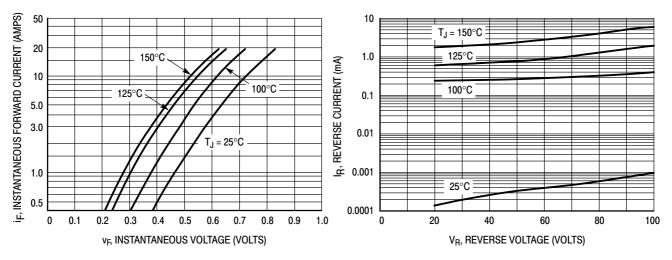


Figure 1. Typical Forward Voltage Per Diode

Figure 2. Typical Reverse Current Per Diode

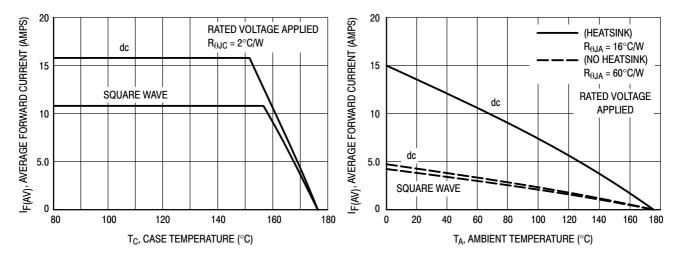


Figure 3. Typical Current Derating, Case, Per Leg

Figure 4. Typical Current Derating, Ambient, Per Leg

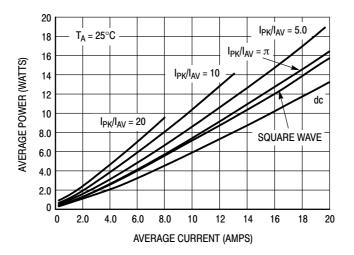
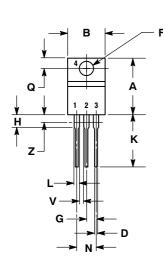
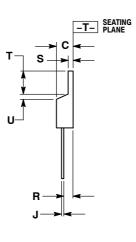


Figure 5. Average Power Dissipation and Average Current

PACKAGE DIMENSIONS

TO-220 CASE 221A-09 **ISSUE AF**





NOTES

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: INCH
- DIMENSION Z DEFINES A ZONE WHERE ALL **BODY AND LEAD IRREGULARITIES ARE** ALLOWED.

	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.570	0.620	14.48	15.75	
В	0.380	0.405	9.66	10.28	
С	0.160	0.190	4.07	4.82	
D	0.025	0.035	0.64	0.88	
F	0.142	0.161	3.61	4.09	
G	0.095	0.105	2.42	2.66	
Н	0.110	0.155	2.80	3.93	
J	0.014	0.025	0.36	0.64	
K	0.500	0.562	12.70	14.27	
L	0.045	0.060	1.15	1.52	
N	0.190	0.210	4.83	5.33	
Q	0.100	0.120	2.54	3.04	
R	0.080	0.110	2.04	2.79	
S	0.045	0.055	1.15	1.39	
T	0.235	0.255	5.97	6.47	
U	0.000	0.050	0.00	1.27	
٧	0.045		1.15		
Z		0.080		2.04	

STYLE 6: PIN 1. ANODE

- CATHODE 2.
- ANODE
- CATHODE

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